

## **PRODUCT BULLETIN # 20482**

Generic Copy

#### Issue Date: 28-May-2014

TITLE: NCP551, NCV551 DATASHEET SPECIFICATION UPDATE

PROPOSED FIRST SHIP DATE: 28-Aug-2014

AFFECTED CHANGE CATEGORY(S): Datasheet

#### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor sales office or <Bett.Lofts@onsemi.com>

#### NOTIFICATION TYPE:

ON Semiconductor considers this change approved unless specific conditions of acceptance are provided in writing. To do so, contact <quality@onsemi.com>.

#### **DESCRIPTION AND PURPOSE:**

Modification is made on page 3 in the ELECTRICAL CHARACTERISTICS table of the NCP551/D datasheet, Quiescent Current Test Vin condition change. The updated Vin Condition of IQ test parameter does not affect the device design, performance and application

See below the updated value highlighted in Red font.

FROM:

Quiescent Current	lq				μA
(Enable Input = 0 V)		-	0.1	1.0	
(Enable Input = V <sub>in</sub> , I <sub>out</sub> = 1.0 mA to I <sub>o(nom.)</sub> )		-	4.0	8.0	

TO:			-	-	
Quiescent Current	Ι <sub>Q</sub>				μΑ
(Enable Input = 0 V)		-	0.1	1.0	
(Enable Input = V <sub>in</sub> , I <sub>out</sub> = 1.0 mA to I <sub>o(nom.)</sub> )		-	4.0	8.0	
1.4V-2.0V (Vin=4.0V)				Ĩ.	1 1
2.1V-3.0V (Vin=5.0V)					'
3.1V-4.0V (Vin=6.0V)			ļ		ļ
4.1V-5.0V (Vin=8.0V)					

Purpose of change: Previous conditions did not permit sufficient input voltage for proper testing of the part Quiescent Current parameter.

# **ON Semiconductor**



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#### List of affected General Parts:

NCV551SN14T1G NCV551SN15T1G NCV551SN18T1G NCV551SN25T1G NCV551SN27T1G NCV551SN28T1G NCV551SN30T1G NCV551SN31T1G NCV551SN32T1G NCV551SN33T1G NCV551SN50T1G NCP551SN15T1G NCP551SN18T1G NCP551SN25T1G NCP551SN27T1G NCP551SN28T1G NCP551SN29T1G NCP551SN30T1G NCP551SN31T1G NCP551SN32T1G NCP551SN33T1G NCP551SN50T1G